

# isc N-Channel MOSFET Transistor

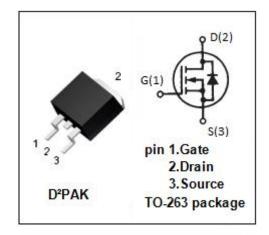
# IXTA100N04T2

### • FEATURES

- Static drain-source on-resistance:
  R<sub>DS</sub>(on) ≤ 7mΩ@V<sub>GS</sub>=10V
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATION

- Current Regulators
- · Solid State Circuit Breakers

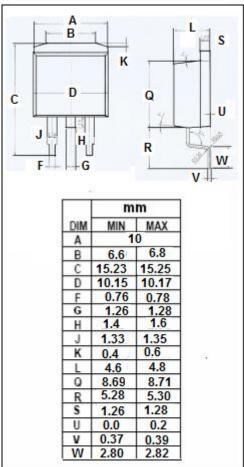


### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	40	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	100	А
I <sub>DM</sub>	Drain Current-Single Pulsed	300	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	150	W
Tj	Operating Junction Temperature	-55~175	°C
T <sub>stg</sub>	Storage Temperature	-55~175	°C

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	1.0	°C/W	





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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	40		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 250 μ A	2.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 25A		7	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		2	- μ Α
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 150°C		50	
Vsp	Diode forward voltage	I <sub>F</sub> = 50A; V <sub>GS</sub> = 0V		1.2	V



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